

EMI2124

Single Pair Common Mode Filter with ESD Protection

Description

The EMI2124 is an integrated common mode filter providing both ESD protection and EMI filtering for high speed serial digital interfaces such as USB2.0.

The EMI2124 provides EMI filtering for one differential data line pair and ESD protection for one data pair plus USB ID pin. It provides a separate Vbus line protection typically used for charging. It is supplied in a small RoHS-compliant WDFN8 package.

Features

- Highly Integrated Common Mode Filter (CMF) with ESD Protection provides protection and EMI Reduction for systems using high speed Serial Data Lines with cost and space savings over Discrete Solutions
- Large Differential Mode Bandwidth with Cutoff Frequency > 2 GHz
- High Common Mode Stop Band Attenuation: >25 dB at 700 MHz, >30 dB at 800 MHz Typical
- Provides Data Lines ESD Protection to IEC61000-4-2 Level 4, ±12 kV Contact Discharge
- Provides V_{ID} & V_{BUS} ESD Protection to IEC61000-4-2 Level 4, ±30 kV Contact Discharge
- Low Channel Input Capacitance provides Superior Impedance Matching Performance
- Low Profile Package with Small Footprint in WDFN8 2.0 mm length x 2.2 mm width x 0.75 mm height Pb-Free Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

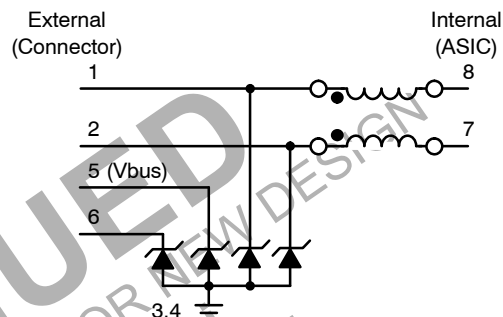
- USB2.0 and other High Speed Differential Data Lines in Mobile Phones and Digital Still Cameras
- MIPI D-PHY



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SIMPLIFIED SCHEMATIC



MARKING DIAGRAM



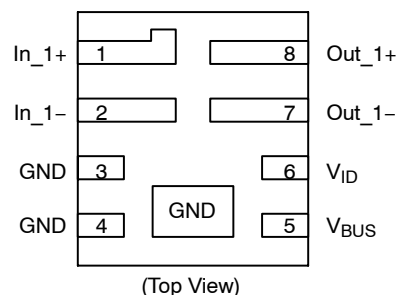
**WDFN8
CASE 511BN**



C3 = Specific Device Code
M = Date Code
■ = Pb-Free Device

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping†
EMI2124MTTAG	WDFN8 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PIN DESCRIPTION

Pin No.	Pin Name	Type	Description
1	In_1+	I/O	CMF Channel 1+ to Connector (External)
2	In_1-	I/O	CMF Channel 1- to Connector (External)
8	Out_1+	I/O	CMF Channel 1+ to ASIC (Internal)
7	Out_1-	I/O	CMF Channel 1- to ASIC (Internal)
5	V _{BUS}	I/O	Supply Protection to Connector – V _{BUS} (External – V _{BUS})
6	I _D	I/O	Supply Protection to Connector (External – V _{ID})
3,4	GND	GND	Ground

MAXIMUM RATINGS (T_A = 25°C unless otherwise stated)

Parameter	Symbol	Value	Units
Operating Temperature Range	T _{OP}	–40 to +85	°C
Storage Temperature Range	T _{STG}	–65 to +150	°C
Maximum Lead Temperature for Soldering Purposes (1/8" from Case for 10 Seconds)	T _L	260	°C
DC Current per Line	I _{LINE}	100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Channel Leakage Current	I_{LEAK}	$T_A = 25^\circ\text{C}$, $V_{IN} = 5\text{ V}$, $\text{GND} = 0\text{ V}$			1.0	μA
Channel Negative Voltage	V_F	$T_A = 25^\circ\text{C}$, $I_F = 10\text{ mA}$	0.1		1.5	V
Channel Input Capacitance to ground (Pins 1,2,8,7 to GND)	C_{IN}	$T_A = 25^\circ\text{C}$, At 1 MHz, $\text{GND} = 0\text{ V}$, $V_{IN} = 1.65\text{ V}$		0.8	1.3	pF
Channel Resistance (Pins 1–8, 2–7)	R_{ch}			8.0		Ω
Differential Mode Cut – Off Frequency	f_{3dB}	50 Ω source and load termination		2.0		GHz
Common Mode Stop Band Attenuation	F_{atten}	@ 800 MHz		30		dB
In-system ESD Withstand Voltage a) Contact discharge per IEC 61000-4-2 standard, Level 4 (External Pins – Pin1, Pin2) b) Contact discharge per IEC 61000-4-2 standard, Level 1 (Internal Pins) c) Contact discharge per IEC 61000-4-2 standard, Level 4 (External Pins – V_{BUS}, V_{ID})	V_{ESD}	(Notes 1 and 2)	± 12 ± 2 ± 30			kV
TLP Clamping Voltage – pin1, pin2 (See Figure 10)	V_{CL}	Forward $I_{PP} = 8\text{ A}$ Forward $I_{PP} = 12\text{ A}$ Reverse $I_{PP} = -8\text{ A}$ Reverse $I_{PP} = -12\text{ A}$		13 16 -6 -8.5		V V V V
TLP Clamping Voltage – V_{BUS} (See Figure 11)	V_{CL}	Forward $I_{PP} = 8\text{ A}$ Forward $I_{PP} = 12\text{ A}$ Reverse $I_{PP} = -8\text{ A}$ Reverse $I_{PP} = -12\text{ A}$		23 25 -4 -5.4		V V V V
Reverse Working Voltage (Pins 1,2,8,7 and 6)	V_{RWM}	(Note 3)			5.0	V
Breakdown Voltage (Pins 1,2,8,7 and 6)	V_{BR}	$I_T = 1\text{ mA}$; (Note 4)	5.5		9.0	V
Reverse Working Voltage (V_{BUS})	$V_{RWM(2)}$	(Note 3)			12	V
Breakdown Voltage (V_{BUS})	$V_{BR(2)}$	$I_T = 1\text{ mA}$; (Note 4)	15		16.8	V
Maximum Peak Pulse Current (V_{ID} to GND)	I_{PP}	8x20 μs Waveform			12	A
Clamping Voltage (V_{ID} to GND)	V_C	$I_{PP} = 5\text{ A}$			10	V
Maximum Peak Pulse Current (V_{BUS} to GND)	$I_{PP(2)}$	8x20 μs Waveform			5	A
Clamping Voltage (V_{BUS} to GND)	$V_{C(2)}$	$I_{PP} = 5\text{ A}$		25		V
Dynamic Resistance Positive Transients Negative Transients	R_{DYN}	$T_A = 25^\circ\text{C}$, $I_{PP} = 1\text{ A}$, $t_P = 8/20\text{ }\mu\text{s}$, Any I/O to GND		0.67 0.59		Ω Ω

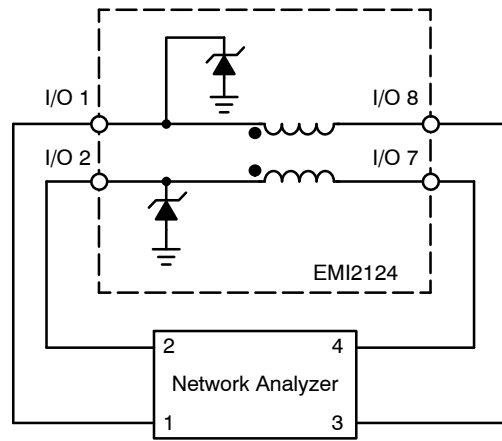
1. Standard IEC 61000-4-2 with $C_{Discharge} = 150\text{ pF}$, $R_{Discharge} = 330$, GND grounded.

2. These measurements performed with no external capacitor.

3. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

4. V_{BR} is measured at pulse test current I_T .

EMI2124



Normal (Differential) Mode

Figure 1. Normal (Differential) Mode Test Configuration

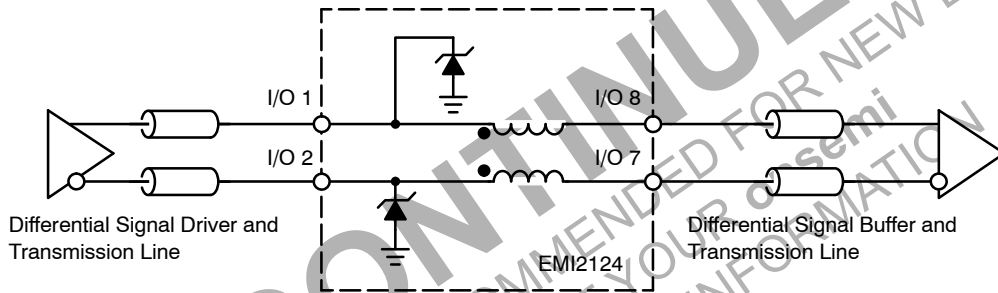


Figure 2. Application Circuit

TYPICAL CHARACTERISTICS

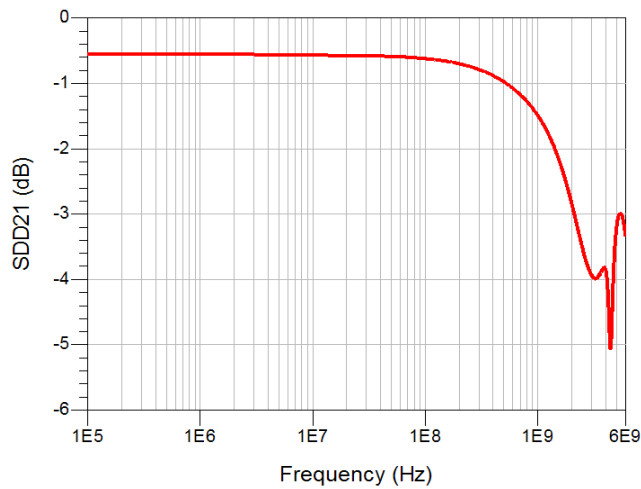


Figure 3. Differential Mode Attenuation vs. Frequency ($Z_{diff} = 100 \Omega$)

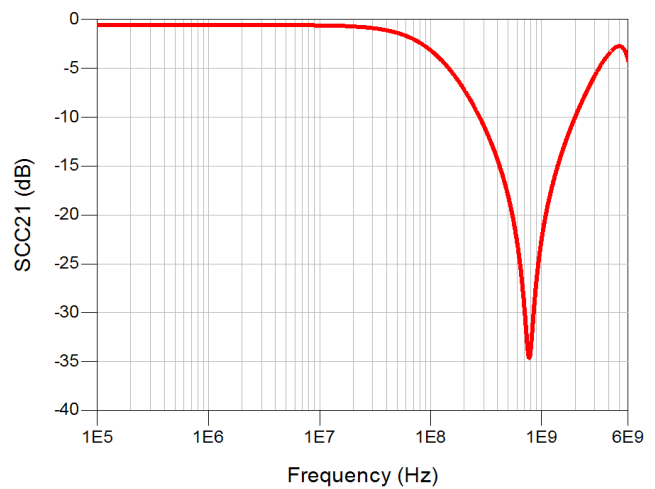


Figure 4. Common Mode Attenuation vs. Frequency ($Z_{comm} = 50 \Omega$)

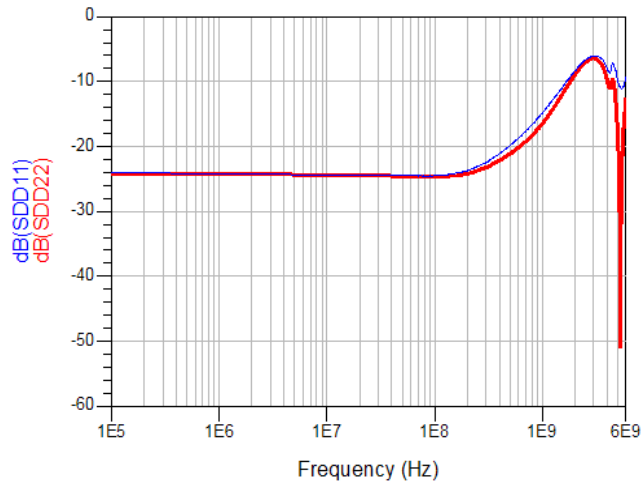


Figure 5. Differential Return Loss vs. Frequency ($Z_{diff}=100 \Omega$)

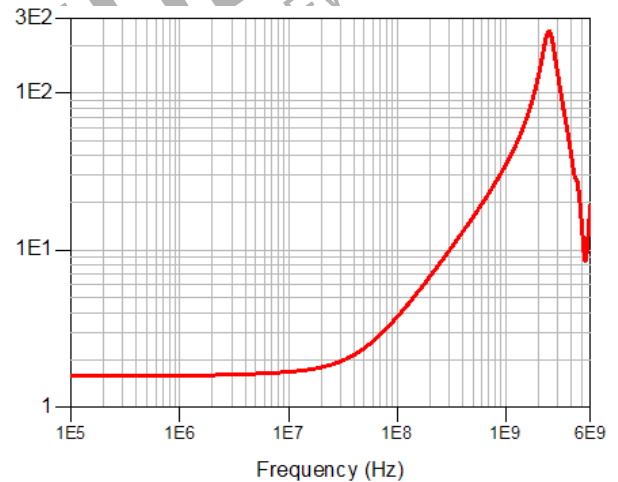


Figure 6. Differential Impedance vs. Frequency ($Z_{diff}=100 \Omega$)

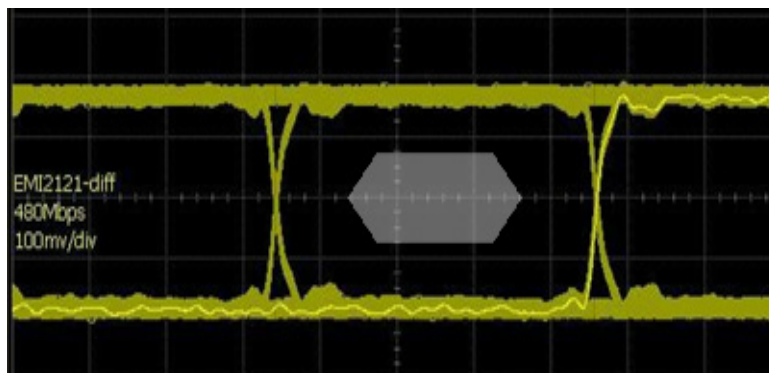


Figure 7. EMI2124 Measured Eye Diagram @ 480 Mbps

Transmission Line Pulse (TLP) Measurements

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 8. TLP I-V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10 s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 9 where an 8 kV IEC61000-4-2 current waveform is compared with TLP current pulses at 8 and 16 A. A TLP curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. Typical TLP I-V curves for the EMI2124 are shown in Figure 10.

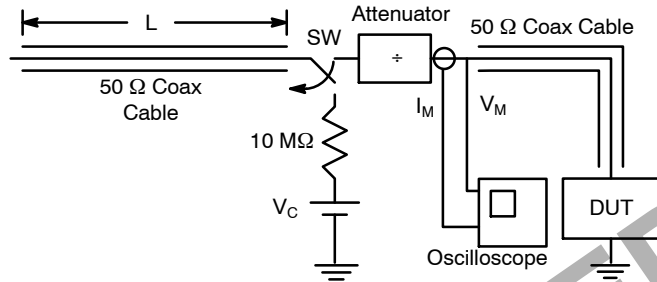


Figure 8. Simplified Schematic of a Typical TLP System

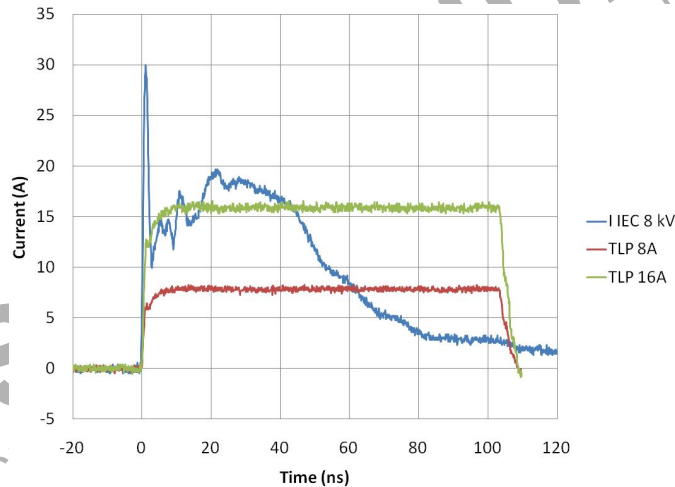


Figure 9. Comparison Between 8 kV IEC61000-4-2 and 8 A and 16 A TLP Waveforms

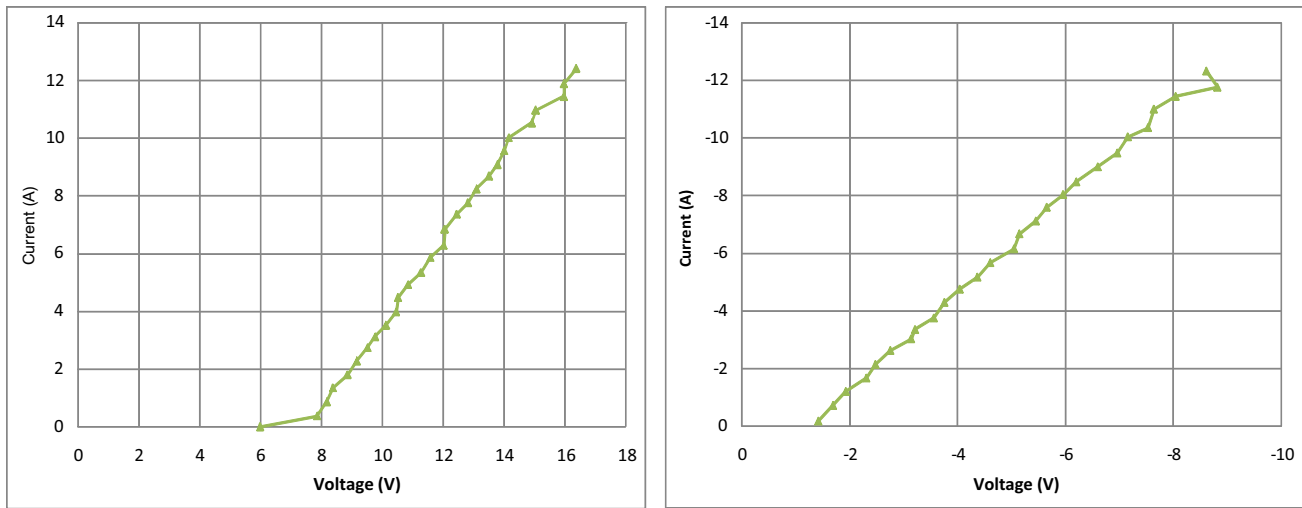


Figure 10. Positive and Negative TLP Waveforms (Pin1, Pin2)

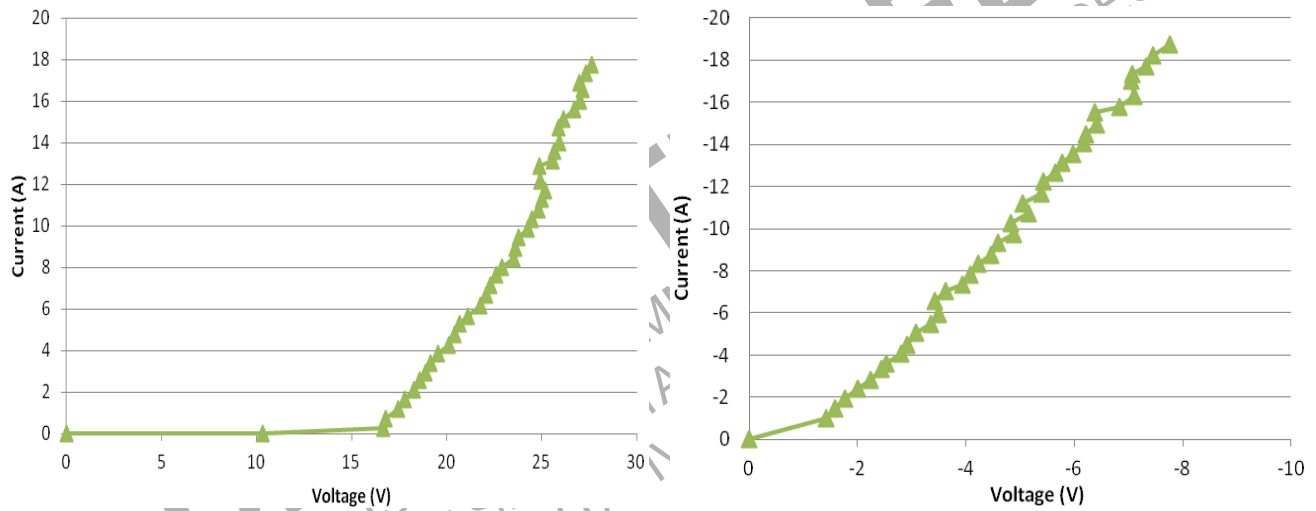


Figure 11. Positive and Negative TLP Waveforms (V_{BUS})

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to On Semiconductor Application Notes AND8307/D and AND8308/D.

IEC61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

IEC61000-4-2 Waveform

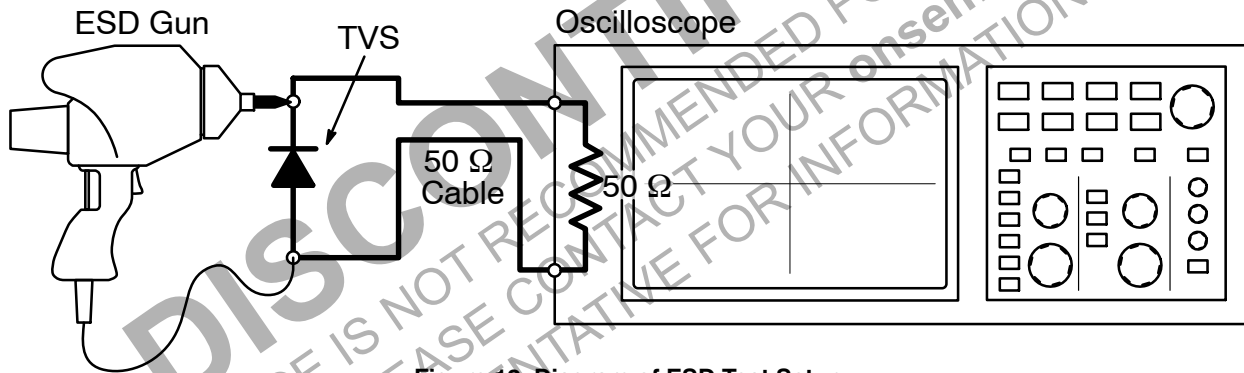
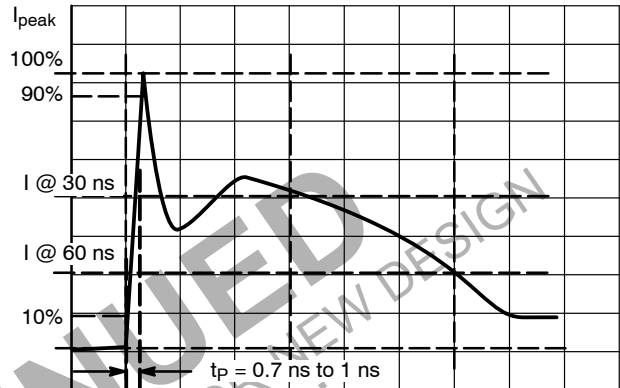


Figure 12. Diagram of ESD Test Setup

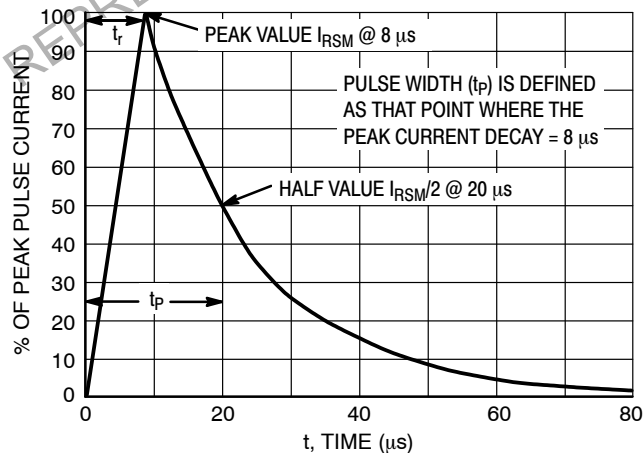


Figure 13. 8 x 20 μ s Pulse Waveform

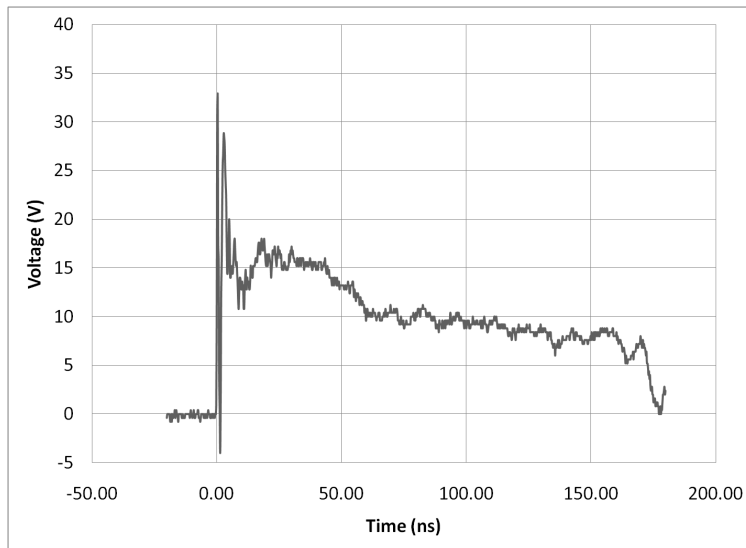


Figure 14. ESD Clamping Voltage +8 kV per IEC6100-4-2 (external to internal pin)

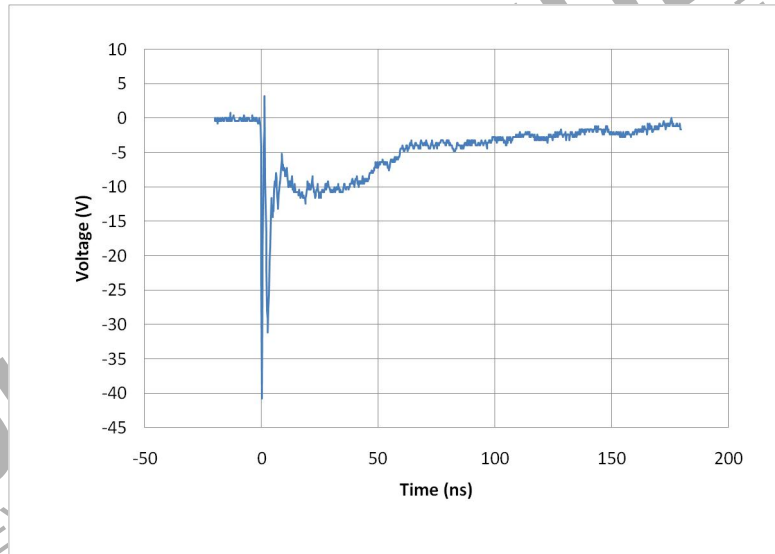


Figure 15. ESD Clamping Voltage -8 kV per IEC6100-4-2 (external to internal pin)

EMI2124

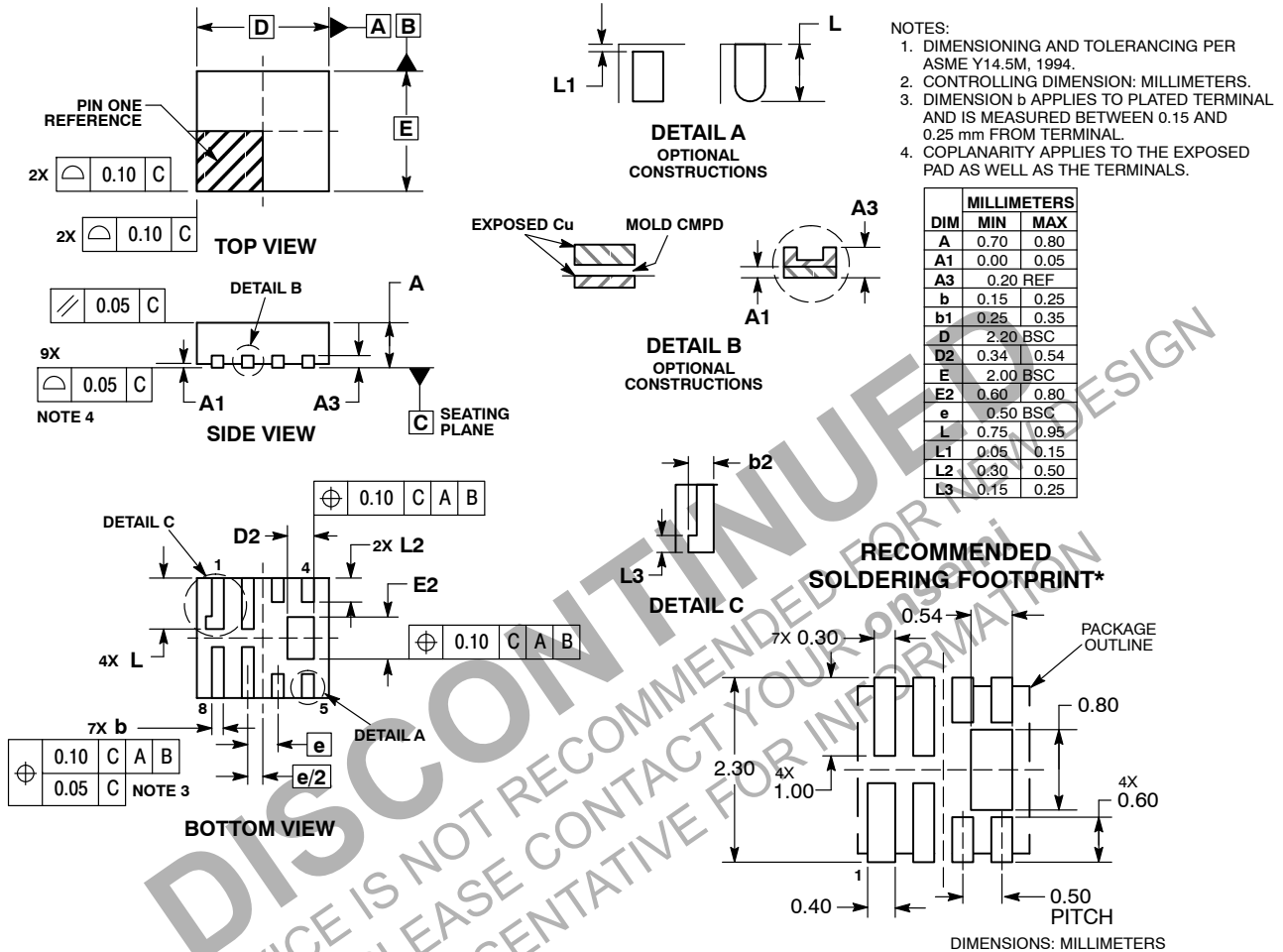
REVISION HISTORY

Revision	Description of Changes	Date
1	EMI2124MTTAG OPN Marked as Discontinued	7/15/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

DISCONTINUED
THIS DEVICE IS NOT RECOMMENDED FOR NEW DESIGN
PLEASE CONTACT YOUR onsemi
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PACKAGE DIMENSIONS

WDFN8, 2.2x2, 0.5P
CASE 511BN-01
ISSUE O

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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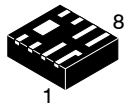
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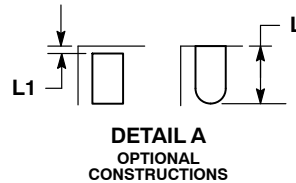
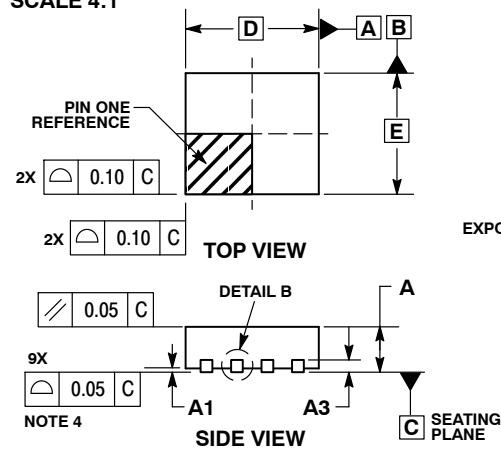
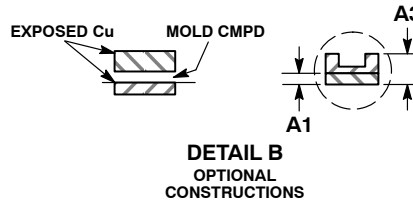
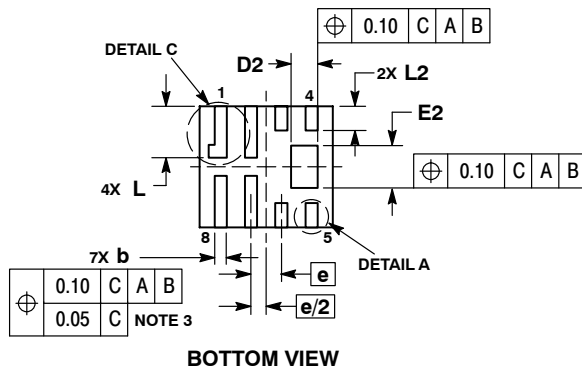
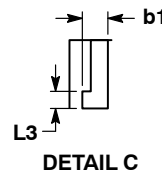
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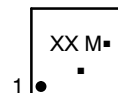
WDFN8, 2.2x2, 0.5P
CASE 511BN
ISSUE A

DATE 11 DEC 2012


DETAIL A
OPTIONAL
CONSTRUCTIONS

DETAIL B
OPTIONAL
CONSTRUCTIONS

BOTTOM VIEW

DETAIL C
NOTES:

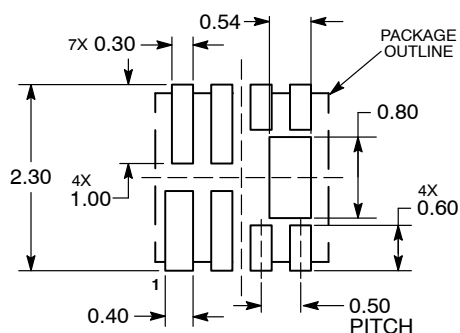
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25 mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.70	0.80
A1	0.00	0.05
A3	0.20	REF
b	0.15	0.25
b1	0.25	0.35
D	2.20	BSC
D2	0.34	0.54
E	2.00	BSC
E2	0.60	0.80
e	0.50	BSC
L	0.75	0.95
L1	0.05	0.15
L2	0.30	0.50
L3	0.15	0.25

GENERIC
MARKING DIAGRAM*


- XX = Specific Device Code
M = Date Code
▪ = Pb-Free Device

*This information is generic. Please refer to device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "▪", may or may not be present.

RECOMMENDED
SOLDERING FOOTPRINT*


DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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